

PATENT  
3811-0127P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: LEE, Jin Gyu et al                      Conf.:  
Appl. No.: NEW    Group:  
Filed: October 16, 2003                      Examiner:  
For: SILOXANE-BASED RESIN AND METHOD OF  
FORMING AN INSULATING FILM BETWEEN  
INTERCONNECT LAYERS OF A SEMICONDUCTOR  
DEVICE USING THE SAME

PRELIMINARY AMENDMENT

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

October 16, 2003

Sir:

The following preliminary amendments and remarks are respectfully submitted in connection with the above-identified application.

This amendment includes:

Amendments to the Specification

Remarks